POLITECNICO DI TORINO Repository ISTITUZIONALE

Work function tuning in hydrothermally synthesized vanadium-doped MoO3 and Co3O4 mesostructures for energy conversion devices

Original Work function tuning in hydrothermally synthesized vanadium-doped MoO3 and Co3O4 mesostructures for energy conversion devices / Feste, P. D.; Crisci, M.; Barbon, F.; Tajoli, F.; Salerno, M.; Drago, F.; Prato, M.; Gross, S.; Gatti, T.; Lamberti, F In: APPLIED SCIENCES ISSN 2076-3417 11:5(2021), pp. 1-13. [10.3390/app11052016]
Availability: This version is available at: 11583/2977478 since: 2023-03-27T13:46:16Z
Publisher: MDPI
Published DOI:10.3390/app11052016
Terms of use:
This article is made available under terms and conditions as specified in the corresponding bibliographic description in the repository
Publisher copyright

(Article begins on next page)





Article

Work Function Tuning in Hydrothermally Synthesized Vanadium-Doped MoO₃ and Co₃O₄ Mesostructures for Energy Conversion Devices

Pietro Dalle Feste ^{1,2,†}, Matteo Crisci ^{1,3,†}, Federico Barbon ¹, Francesca Tajoli ¹, Marco Salerno ⁴, Filippo Drago ⁵, Mirko Prato ⁴, Silvia Gross ^{1,2,6,*}, Teresa Gatti ^{3,7,*} and Francesco Lamberti ^{1,2,*}

- Department of Chemical Sciences, University of Padova, Via Marzolo 1, 35131 Padova, Italy; pietro.dallefeste@unipd.it (P.D.F.); matteo.crisci@studenti.unipd.it (M.C.); federico.barbon@unipd.it (F.B.); francesca.tajoli@phd.unipd.it (F.T.)
- Interdepartmental Centre Giorgio Levi Cases for Energy Economics and Technology, University of Padova, Via Marzolo 9, 35131 Padova, Italy
- Institute of Physical Chemistry, Justus Liebig University Giessen, 35390 Giessen, Germany
- Materials Characterization Facility, Italian Institute of Technology, Via Morego 30, 16163 Genova, Italy; marco.salerno@iit.it (M.S.); mirko.prato@iit.it (M.P.)
- ⁵ Nanochemistry, Italian Institute of Technology, Via Morego 30, 16163 Genova, Italy; filippo.drago@iit.it
- Karlsruher Institut für Technologie (KIT), Institut für Technische Chemie und Polymerchemie (ITCP), 76131 Karlsruhe, Germany
- Center for Materials Research, Justus Liebig University Giessen, 35390 Giessen, Germany
- Correspondence: silvia.gross@unipd.it (S.G.); teresa.gatti@phys.chemie.uni-giessen.de (T.G.); francesco.lamberti@unipd.it (F.L.)
- † These two authors contributed equally.

Abstract: The wide interest in developing green energy technologies stimulates the scientific community to seek, for devices, new substitute material platforms with a low environmental impact, ease of production and processing and long-term stability. The synthesis of metal oxide (MO) semiconductors fulfils these requirements and efforts are addressed towards optimizing their functional properties through the improvement of charge mobility or energy level alignment. Two MOs have rising perspectives for application in light harvesting devices, mainly for the role of charge selective layers but also as light absorbers, namely MoO₃ (an electron blocking layer) and Co₃O₄ (a small band gap semiconductor). The need to achieve better charge transport has prompted us to explore strategies for the doping of MoO₃ and Co₃O₄ with vanadium (V) ions that, when combined with oxygen in V₂O₅, produce a high work function MO. We report on subcritical hydrothermal synthesis of V-doped mesostructures of MoO₃ and of Co₃O₄, in which a tight control of the doping is exerted by tuning the relative amounts of reactants. We accomplished a full analytical characterization of these V-doped MOs that unambiguously demonstrates the incorporation of the vanadium ions in the host material, as well as the effects on the optical properties and work function. We foresee a promising future use of these materials as charge selective materials in energy devices based on multilayer structures.

Keywords: metal oxide; doping; semiconductor; work function tuning; energy device



Citation: Dalle Feste, P.; Crisci, M.;
Barbon, F.; Tajoli, F.; Salerno, M.;
Drago, F.; Prato, M.; Gross, S.; Gatti,
T.; Lamberti, F. Work Function Tuning
in Hydrothermally Synthesized
Vanadium-Doped MoO₃ and Co₃O₄
Mesostructures for Energy
Conversion Devices. *Appl. Sci.* 2021,
11, 2016. https://doi.org/10.3390/
app11052016

Academic Editor: Minas M. Stylianakis

Received: 16 January 2021 Accepted: 22 February 2021 Published: 25 February 2021

Publisher's Note: MDPI stays neutral with regard to jurisdictional claims in published maps and institutional affiliations.



Copyright: © 2021 by the authors. Licensee MDPI, Basel, Switzerland. This article is an open access article distributed under the terms and conditions of the Creative Commons Attribution (CC BY) license (https://creativecommons.org/licenses/by/4.0/).

1. Introduction

Transition metal oxides are a multifaceted and diversified class of inorganic materials whose chemico-physical, structural and functional properties encompass a very wide range of different features [1–4]. From the structural point of view, also depending on their stoichiometry, they display very different structures, such as, for instance, (the most common) NaCl, rutile, corundum, fluorite, spinel and cuprite structures. As far as their electric behavior is concerned, it ranges from superconductors (e.g., high- T_c copper oxides), to good metallic conductors (e.g., V_2O_3 , ReO_3) through to semiconductors (e.g., NiO, ZnO,

Appl. Sci. 2021, 11, 2016 2 of 13

TiO₂, VO₂) and they can also display interesting magnetic (e.g., Fe₃O₄), and electrochromic (e.g., WO₃) characters [2,3]. From the chemical point of view, their properties span the full range, from acidic through amphoteric to basic. These chameleonic features allow these materials to be widely used in commercial products combined to their thermal and chemical stability, ease of processing, and excellent mechanical robustness [5–9].

Focusing on the semiconducting materials, there is flourishing research in the optimization of electronic properties of metal oxides in order to fulfill the stringent requirements of next generation clean energy conversion devices such as solar cells [10].

This is the case, for example, of MoO_3 and Co_3O_4 , that show different electrical properties [11–15] but present one issue: the low mobility of charge carriers. In fact, both oxides are used in photovoltaics for different reasons. First, MoO₃ is a n-type semiconductor; however, due to the high band gap (about 3 eV [16]) and a work function similar to that of Au (5.1 eV or higher depending on conditions in which it is measured [17,18]), it is commonly used as hole transporting material (HTM) and/or as blocking layer for hampering photocharges recombination together with other more conductive HTM. This feature increases the overall cost of device production in terms of money and time consumption. In addition, the charge mobility that affects the actual conductivity of the material is strongly dependent on the exact stoichiometry: the electron conductivity in MoO₃ is almost zero $(10^{-7} \,\mathrm{S\,cm^{-1}})$, whereas in the oxygen-poor MoO_{3-x} species, the conductivity can be pushed up by several orders of magnitude, reaching 10^4 S cm⁻¹ in pure MoO₂ [19,20]. These results are in agreement with the fact that the atmospheric conditions (mainly either vacuum or ambient) dramatically change the valence/conduction band (VB/CB) values estimation measured with conventional spectroscopic techniques, with a remarkable variation found in the literature that inevitably affects the design of device architectures [17,18]. On the other hand, the spinel Co_3O_4 shows a similar low hole mobility (order of 10^{-5} S cm⁻¹), slightly higher due to the presence of a double electronic direct band gap that allows the oxide to have the proper band gap value (about 1.5 eV) to be directly used as a light absorber and HTM in a pn junction-based next generation all-oxide solar cell [21–24].

As previously mentioned, the charge conductivity is the bottleneck for the real implementation of these oxides in high-performance energy-conversion devices. There are two main strategies used for improving the conductivity of thin films based on these materials: (i) improvement in the quality of the film morphology (i.e., by grain boundaries engineering) and (ii) chemical doping [25] of the metal oxide (MO) constituting the film with heteroatoms to accomplish band engineering instead. Among the different doping elements, specific transition metal ions such as Mn, Fe, Cu, Co, Cr [26–28] are the most promising ones because of the number of oxidation states available that can in principle tune the electronic properties of the host MO. Our choice in this work was addressed towards an aliovalent vanadium (V) substitution, because this metal can be easily oxidized to its pentavalent form in V_2O_5 , a MO that possesses a work function between 6.4 eV and 7 eV [29]). In this way, other MOs that contains V(V) ions as dopants could be likely p-doped, thus improving their charge mobility, as occurred in some examples in the literature involving vanadium and MoO₃ [30].

In the literature, the doping of Co_3O_4 has been previously performed using different elements such as Ru, N, La, Sn, Cu, Li, Ag, V and adopting various synthetic/deposition/processing approaches, such as co-precipitation [31], plasma treatment [32], spin coating [33], spray coating [34], dip coating [35], magnetron sputtering [36], thermal decomposition [37], and solvothermal or hydrothermal synthesis [38–41]. This last synthetic methodology is the most valuable among the others because it can be carried out under green conditions (water-based solutions) at low costs (i.e., with simple wet-chemistry laboratory equipment and easy chemical procedures), and typically pursues the fast crystallization of materials already under low temperature subcritical conditions. Moreover, it allows for a good control over reaction conditions (such as the fine tuning of the dopant concentration), while ensuring high yields. However, only a few syntheses are reported in the literature for the preparation of V-doped Co_3O_4 . Magnetron sputtering [36] is suitable for direct film deposition, but is not usable to obtain

Appl. Sci. 2021, 11, 2016 3 of 13

materials to be subsequently processed through a solution-based technique. A case of V-doped Co_3O_4 synthesized hydrothermally is reported in the literature for catalytic purposes [41], but the electronic properties are not described, thus remaining hitherto uncharacterized. On the other hand, starting from a theoretical analysis that predicts the possibility of balancing the oxygen vacancies in the lattice, [42] MoO_3 has been doped using both chemical and physical deposition techniques such as CVD [43], the sol-gel method [44], the solution combusted method [45], magnetron sputtering [46], and also hydrothermal routes [47,48], similar to Co_3O_4 . This last procedure is widely applied for realizing doped Mo_3O_4 samples with different elements such as Ni [43,45], S [49] and a range of other transition metals [50–52] and in particular, vanadium [30].

In this work, we describe the subcritical hydrothermal synthesis of V-doped Co_3O_4 micro-wires and MoO_3 micro-lamellae starting from water soluble precursors (followed by a calcination step), with the aim of finely tuning the electronic properties of these MO semiconductors to improve their potential for exploitation in energy-related devices. We also report on the outcomes obtained by implementing a systematic variation in concentration of the introduced dopants (from 1% to 20% at. with respect to the host oxide), which happen to be significantly different for the two investigated MO host matrices, allowing us to draw preliminary conclusions on the arrangement of the vanadium guest species within the two different crystalline lattices. We also show that such a tuning of the doping level in these semiconducting MOs can lead to a parallel tuning of the Fermi level towards the realization of materials with a higher work function compared to the undoped analogues, with interesting perspectives for applications in energy-conversion devices.

2. Results and Discussion

In Figure 1, a scheme of the hydrothermal synthesis used to prepare V-doped MoO_3 and Co_3O_4 mesostructures is presented (experimental details are provided in the Experimental Section). In the first step, the precursors of cobalt or molybdenum and vanadium are dissolved in water together with the vanadium precursor. During the second step, a precipitating agent is added under solution stirring. Next, a Teflon reactor containing the mixture is sealed in a Teflon-lined stainless-steel reactor and heated at 150 °C for a set time to perform the hydrothermal reaction in the third step. The separated powders are finally calcined to yield the final V-doped and undoped (for reference) MOs (Co_3O_4 :V and MoO_3 :V).

The samples obtained by this procedure are characterized by powder X-Ray diffraction (P-XRD) to verify the formation of the desired phase (cubic for Co₃O₄, space group Fd-3m (227), orthorhombic for MoO_3 , (α - MoO_3), space group Pbnm (62)). Figure 2a shows the diffractogram of undoped Co₃O₄, confirming the presence of the cubic Co₃O₄ phase (PDF 74-1657), with a unit cell parameter a estimated by Pawley refinement (Figure S3a) of 8.0838 ± 0.0014 Å (Figure S3a). The reflections located at $2\theta = 19^{\circ}$, 31.2° , 36.8° , 38.6° , 44.8° , 55.7° , 59.5° and 65.3° are attributed to the planes (1 1 1), (2 2 0), (3 1 1), (2 2 2), (4 0 0), (4 2 2), (5 1 1) and (4 4 0) of Co₃O₄, respectively [53]. Diffractograms of V-doped samples (Figure S1 in the Supporting Information—S.I.) show the cubic Co₃O₄ pattern and no other phases are detected, nor a shift of the reflections' positions as a consequence of V-doping. An additional phase is detected only at the highest nominal concentration of dopant (i.e., 20% at.), as shown in Figure 2b, where weak reflections appear at $2\theta = 20.3^{\circ}$, 26.2°. Specifically, they are ascribable to the lattice planes (0 0 1), (1 1 0) of crystalline orthorhombic V₂O₅ (PDF 41-1426) [54], indicating the formation of a second and separated MO phase in the synthetized material when a relatively high amount of V-precursor is introduced in the reaction mixture. The textural characterization with scanning electron microscopy (SEM, Figure 2c) discloses the peculiar morphology of this synthesized Co₃O₄, constituted of particles of some tens of nm fused together to generate individual microwires (cross-section is in the nanoscale). To the best of our knowledge, a similar hierarchical arrangement of Co₃O₄ nanoparticles (of which many examples exist [55,56] also in the form of nanowires [57,58]) into longer wire-like structures has never been reported before. Appl. Sci. 2021, 11, 2016 4 of 13

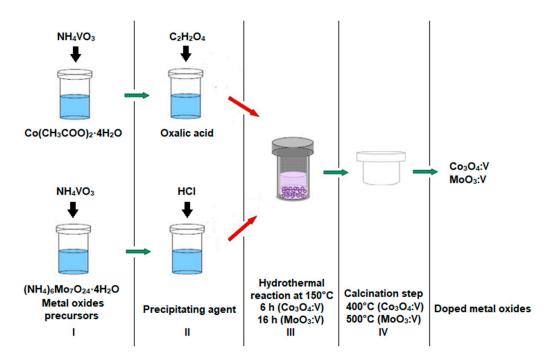


Figure 1. Schematic representation of the hydrothermal synthesis procedure used in this work to obtain two metal oxides MOs with vanadium guest species, namely Co_3O_4 :V and MoO_3 :V.

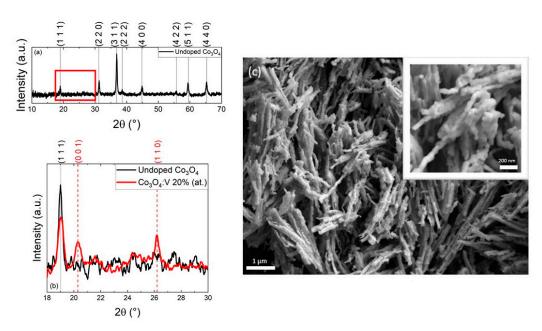


Figure 2. (a) Powder X-Ray diffraction (P-XRD) diffractogram of hydrothermally synthesized undoped Co_3O_4 , after the calcination step. (b) Zoom on the 18° – 30° 20 range of the same diffractogram and comparison with that of the Co_3O_4 :V 20% at sample. (c) Field-emission scanning electron microscopy (FE-SEM) image of a typical Co_3O_4 :V sample (20% at) showing the micro-wire-like morphology. The inset shows a magnified area where the particle-like sub-units of the micro-wires are evidenced.

Figure 3 shows the P-XRD patterns of the undoped MoO₃ and MoO₃:V 20% at. samples (respectively, in Figure 3a,b). The reflections correspond to those of the orthorhombic MoO₃ α -phase (PDF 65-2421) with calculated unit cell parameters of $a=3.9602\pm0.0003$ Å, $b=13.8540\pm0.0011$ Å, $c=3.6949\pm0.0002$ Å estimated by Pawley refinement (Figure S3b). However, this analysis shows that a mixture of orthorhombic (α -MoO₃) and monoclinic (β -MoO₃, PDF 85-2405) phases of MoO₃ is present in the sample. Major diffraction peaks

Appl. Sci. **2021**, 11, 2016 5 of 13

(with relative lattice planes) corresponding to the desired phase, α -MoO3, can be seen at 12.8°, 23.4°, 25.8°, 27.4°, 33.8°, and 39° 20, relative to the planes (0 2 0), (1 1 0), (0 4 0), $(0\ 2\ 1)$, $(1\ 0\ 1)$ and $(0\ 6\ 0)$, respectively. In Figure 3b, two low intensity Bragg peaks at 21.6° and 24.9° 20 are clearly visible in the V 20 % at. nominal doped diffractogram. From a search and match procedure, these could be related to the presence of V₉Mo₆O₄₀ (PDF 34-0527) which is also well fitted in the Pawley refinement (Figure S3c). The absence of such a phase in the samples with a lower percentage of nominal doping could be related to the instrumental detection limit, or the polyoxovanadate could be present in an amorphous state. No shift of the reflections is evident (as can be seen in Figure 3b and from the complete set of diffractograms in Figure S1), so the amount of substitutional V⁵⁺ ions for Mo⁶⁺ ions might be negligible. Moreover, the calculated lattice parameters for the MoO₃: V 20% at. sample (Figure S3c) differ by less than 0.01 Å with respect to the pure compound, proving that the structural change in the unit cell is very limited. In Figure 3c, an SEM image of a V-doped MoO₃ sample is shown, highlighting the presence of lamellar structures of highly variable dimensions in the order of the µm, similar to what was obtained elsewhere in the literature [59]: this structural variability can be due to the calcination step, which promotes the coalescence of the smaller objects with the bigger ones, leading to a non-homogenous distribution of size.

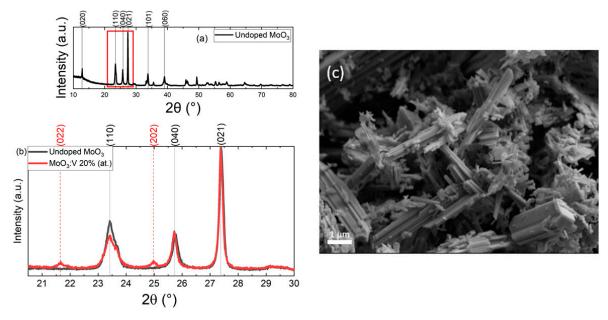


Figure 3. (a) P-XRD diffractogram of hydrothermally synthesized undoped MoO₃. (b) Zoom on the 20.5° – 30° 2θ range of the same diffractogram and comparison with that of the MoO₃:V 20% at. sample. (c) SEM image of a typical MoO₃:V sample (20% at.) showing the micro-lamellar-like morphology.

The hydrothermally synthesized and subsequently calcinated MO samples are optically characterized by diffuse reflectance spectroscopy. The recorded spectra are reported in Figure S2 in the S.I. The spectra of Co_3O_4 :V samples present two characteristic bands at 700 and 400 nm, attributed to a charge transfer transition from oxygen to the metal center, namely from O^{2-} to Co^{3+} and from the O^{2-} to Co^{2+} , respectively [60]. It is worth to mention that, among other MOs, Co_3O_4 is particularly sensitive to oxygen due to the simultaneous presence of Co^{2+} and Co^{3+} ions that affect the oxygen content within the lattice. It has been proved that the amount of oxygen can be tuned by the addition of heteroatoms, by treatment with plasma or with different gases [61–63]; however, stabilizing the oxygen vacancy in Co_3O_4 remains challenging and specific advanced structural characterization is required in order to characterize it, such as synchrotron extended X-ray absorption fine structure (EXAFS) or X-ray absorption near edge fine structure (XANES).

Appl. Sci. **2021**, 11, 2016 6 of 13

From the reflectance spectra, a further analysis allows one to determine the band gap energy using the Tauc plot method [64]. This method is based on the relationship existing between light absorbance and band gap energy, described by the equation $(\alpha hv)^{\frac{1}{\gamma}} = B(hv - E_g)$ [65], where α is the absorption coefficient, hv is the incident photon energy, E_g is the energy of the band gap and ν is a constant; γ is equal to 1/2 for direct transitions or 2 for indirect ones. In this case, the reflectance spectra are transformed into the corresponding absorption spectra using the Kubelka–Munk Function $(F(R_\infty))$. In the Tauc plots presented in Figure 4a, the product $(F(R_\infty)hv)^{\frac{1}{\gamma}}$ (with γ assuming the value of 1/2 for a direct band gap in Co_3O_4) is plotted as a function of the incident photon energy, resulting in the determination of two band gaps for the Co_3O_4 :V samples. The intersection of the linear fit of the Tauc plot with the x-axis, gives the value of the band gap energy, resulting in two band gaps for the Co_3O_4 :V samples.

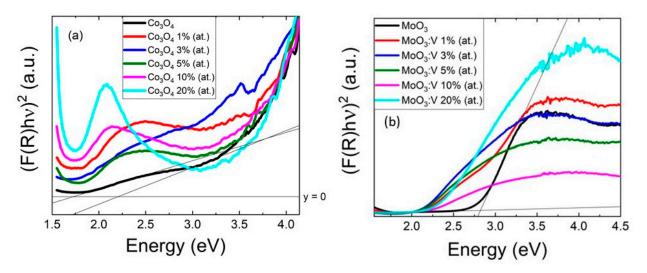


Figure 4. Tauc plot analysis for the (a) Co_3O_4 :V and (b) MoO_3 :V samples series. Grey lines indicates the linear fits used to extrapolate the E_g values.

Reflectance measurements and relative band gap calculations were performed for the MoO₃:V samples as well (reflectance spectra are reported in Figure S2 of the S.I.). In there, a main band around 375 nm (3.3 eV) can be observed only for the undoped sample, which shifts towards higher wavelengths for the doped samples, following an unclear relationship with the doping concentration. Moreover, a narrow and intense peak is found in the near-infrared (NIR) region at approximately 1080 nm (1.1 eV) that was previously attributed to the intervalence charge transfer $Co^{2+} \rightarrow Co^{3+}$ [66]. The Tauc plot is also built for this second MO series (Figure 4b), with the main difference in the γ value used, which in this case is 2 for an indirect band gap semiconductor [65].

The results of all these linear fittings are reported in Table 1. From this analysis, it appears that the bandgap of Co_3O_4 remains almost unvaried, with only a slight increase in the sample doped with 20% at. nominal vanadium. For MoO₃ instead a progressive decrease in the Eg from the undoped material is evident, up to the 10% at. doped sample, after which a plateau is reached as described by the values reported in Table 1, likely as a consequence of a doping saturation effect.

Appl. Sci. 2021, 11, 2016 7 of 13

Table 1. Summary of chemical and electrical properties for the series of hydrothermally synthesized
undoped and V-doped Co_3O_4 and MoO_3 samples investigated in the present study.

Sample	V % ¹	Eg (eV) ² (±4%)	WF (eV) ⁴
Undoped Co ₃ O ₄	-	1.74; 2.24 ³	4.8 ± 0.11
Co ₃ O ₄ :V (1% at)	<1	1.50; 2.20 ³	4.75 ± 0.05
Co ₃ O ₄ :V (3% at)	<1	1.50; 2.20 ³	4.71 ± 0.02
Co ₃ O ₄ :V (5% at)	<1	1.65; 2.14 ³	4.71 ± 0.02
Co ₃ O ₄ :V (10% at)	<1	1.48; 2.35 ³	4.81 ± 0.01
Co ₃ O ₄ :V (20% at)	12	1.63; 2.62 ³	5.15 ± 0.04
Undoped MoO ₃	-	2.8	5.14 ± 0.05
MoO ₃ :V (1% at)	1	2.3	5.34 ± 0.05
MoO ₃ :V (3% at)	3	2.1	5.48 ± 0.08
MoO ₃ :V (5% at)	4	2.1	5.70 ± 0.02
MoO ₃ :V (10% at)	6	2.2	6.10 ± 0.03
MoO ₃ :V (20% at)	13	2.3	6.11 ± 0.02

 $^{^{\}overline{1}}$ Actual vanadium atomic concentration as determined by ICP analysis and calculated as: V % = number of V dopant atoms/100 host metal atoms (namely, Mo or Co); 2 Eg extracted from Tauc plot analysis with a ± 4 % associated error; 3 For Co₃O₄ two Eg values are extracted; 4 Determined by KPM analysis.

The smooth shape of the Tauc plots at band gap edges reveals the presence of shallow defects within the band gap of the investigated vanadium-doped cobalt oxides (attributed to oxygen vacancies as usually happens in oxides) [67], and a substantial shift of $E_{\rm g}$ for the vanadium-doped molybdenum ones, suggesting that electronic properties of these MO semiconductors are affected by vanadium inclusion. Therefore, a more detailed electronic characterization is required to understand the effect of the ionic dopant on the energetics of these species, which can be obtained by Kelvin probe microscopy (KPM), together with a precise analytical determination of the actual quantity of dopants present in the lattice, which can be obtained by Inductively Coupled Plasma Optical Emission Spectrometry (ICP-OES) analysis.

Although similar synthetic conditions were adopted for both the V-doped MOs, we can state with good approximation that only MoO₃ has been successfully incorporated into the matrix, as shown by ICP analysis, whose results are reported in Table 1. In more detail, significantly lower amounts of vanadium are found within the Co₃O₄-based samples with respect to the MoO₃-based ones, despite the nominal doping concentrations being similar. This result is in substantial accordance with the trend in Eg values determined from the Tauc plots, in which the band gap does not change in Co₃O₄, while it decreases with increasing doping in MoO₃, for at least the first three samples (see Figure 4 and Table 1). Furthermore, the ICP analysis highlights that a significative amount of dopant is found already at very low V concentrations in MoO₃. However, a shift towards higher diffraction angles of the reflections in the corresponding XRD patterns is not observed, and only at 20 % at. of nominal doping an additional phase is detected (likely $V_9Mo_6O_{40}$). Therefore, with the present data, it is still difficult to understand whether vanadium ions are present as substitutional with respect to molybdenum or in other forms within the sample. On the contrary, the Co₃O₄ samples do not show any relevant vanadium incorporation except for the 20% at. specimen, which most likely is a biphasic material, i.e., a mixed V₂O₅-Co₃O₄ composite, as anticipated from P-XRD (Figure 2b). The reason for this different doping behavior with respect to the vanadium ion dopants can probably be ascribed to the different crystal structures of the Mos, with α -MoO₃ and V₂O₅ being both orthorhombic whereas Co₃O₄ has a cubic lattice. In light of these considerations, it appears reasonable to foresee an easier accommodation of the V(V) cations in the structure of MoO₃ with respect to that of Co₃O₄. On the other hand, we exclude a pure influence of the ionic radii of the cations

Appl. Sci. 2021, 11, 2016 8 of 13

on the doping efficiency, because these are comparable for all the cations here considered, with the appropriate coordination number (54 pm for V(V) and 59 pm for Mo(VI) with a coordination number VI, being α -MoO₃ constituted by MoO₆ distorted octahedra, 58 pm for high spin Co(II) in T_d coordination and 54.5 pm for high spin Co(III) in O_h coordination, with Co₃O₄ having the typical spinel structure Co^{II}[Co^{III}]₂O₄) [68].

KPM analysis provides a value of the work function (WF), which can substantially vary upon effective chemical doping, and thus provides information on the doping character (p- or n-) in the semiconducting materials. The trends in the WF of the MO materials (Figure 5) are highly related to the optical and ICP data: in the Co₃O₄:V samples series the WF remains practically unchanged (4.7÷4.8 eV) across most doping values except for the highest one, for which a significative variation takes place (from ~4.75 eV up to \sim 5.15 eV). The increased WF being obtained only at the highest V-doping level in $\mathrm{Co_3O_4}$ can be related to the presence of the second V_2O_5 phase formed, which is perhaps located on the external surface of the MO mesostructures, thus largely contributing to the measured value (WF of pure V_2O_5 should be ~7 eV [69]). On the contrary, for the MoO₃ samples, a linear increase in the WF (from 5.14 eV to 6.10 eV) is observed with increasing dopant concentration, for the lowest values thereof, while the WF does not increase further only at the highest concentration (with a 6.11 eV WF value obtained when the nominal amount of vanadium in the MO doubles from 10% at. to 20% at.), thus suggesting also in this case the occurrence of a phase separation within the material as for the case of Co₃O₄:V 20% (at). These results (with the expected doping concentrations corroborated by ICP data), suggest that only in the case of MoO₃ a hypothetical substitutional p-doping of the material is obtained by using the hydrothermal method at low vanadium concentrations (i.e., below 10% at.), whereas for Co₃O₄ any additional determined p-character can be only attributed to the presence of a V_2O_5 phase formed in conjunction. However, an interesting two-phase composite material appears with high crystalline content as revealed by P-XRD, which possesses the characteristics of both the constituents (the E_g of pristine Co_3O_4 and a deeply located Fermi level similar to V_2O_5), what could be useful for photovoltaic applications.

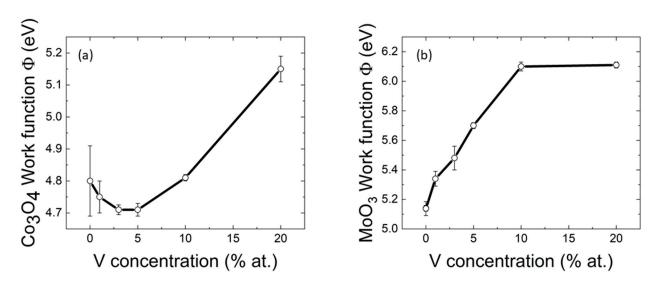


Figure 5. Work function values estimated through Kelvin probe microscopy analysis for the (a) Co_3O_4 :V and (b) MoO_3 :V samples series.

3. Conclusions

In this work, we demonstrated the effect on structural and electrical properties of the incorporation of vanadium ions in MO host materials resorting to a green hydrothermal method that starts from polyoxidometalate or polyoxovanadate and carboxylate precursors. In one case, V ions are incorporated in the MoO₃ lattice up to a relatively high atomic percentage (10% at.). We also showed the effect of such an incorporation on the work

Appl. Sci. 2021, 11, 2016 9 of 13

function of the MO semiconducting scaffold, which results in a progressive (and almost linear) increase (with respect to the vacuum level), thus allowing us to predict an effective p-doping of the material that enables tuning of the charge transport properties of the materials, whose actual determination remains the subject of future work. In addition, it should be pointed out that the nature of the Mo(VI) substitution with aliovalent extrinsic V(V) cations in the lattice is only hypothesized at the moment, and its confirmation would be obtained through X-ray absorption spectroscopy investigations performed at synchrotron, which is a suitable method to investigate the typology of ion incorporation into doped materials.

On the other hand, we showed that a low band gap Co_3O_4 MO semiconductor (also prepared through hydrothermal synthesis) cannot guest V(V) cations into its lattice, although V(V) and Co(II/III) ionic radii are quite similar in dimension, and the modulation of the WF is achievable only when a relatively high concentration of vanadium precursor is added (experimental 12% at.), thus forming a two-phases compound based on V_2O_5 and Co_3O_4 . Although the synthetic goal of this work was mainly demonstrating the possibility of substitutional (or even interstitial) doping of the two considered MO matrices, we will next characterize this Co-V composite further, to better understand its structural features and evaluate its real potential for application in sustainable technologies for conversion of light energy into other useful forms (electricity, solar fuels, but even into light energy storage applications, given the relevance of cobalt oxides in battery-like devices).

4. Experimental Section

All reagents and solvents were purchased from Sigma Aldrich (Darmstadt, Germany), if not otherwise specified, and used as received. Powder X-ray diffraction was carried out on a Bruker D8 Advance Plus diffractometer at the PanLab department facility, founded by the MIUR "Dipartimenti di Eccellenza" grantNExuS. Diffraction data were acquired by employing the Cu K_{α} radiation (Cu anode supplied with 40 kV and a current of 40 mA). A LYNEXEYE XE-T detector with 192 measuring channels in 1D mode was used. The patterns for Co₃O₄-based samples were recorded in the range of 10° –70° with a 0.027° (20) scan step and 0.7 s per step acquisition time. For the Co₃O₄:V 20% at. sample, one additional XRD pattern was recorded in the range of 18° –40° with a 0.027° (20) scan step and 2 s per step acquisition time. The XRD patterns of the MoO₃-based samples were collected in the range of 10° –80° with a 0.014° (20) scan step and 0.3 s acquisition time per step. Fixed divergence slits of 0.50° were used together with Soller slits with a 2.5° aperture.

The crystallographic phase identification was performed by a search and match procedure, using Bruker DIFFRAC.EVA [70] software. The diffractograms were analyzed with the software TOPAS Academic V6 [71] (Bruker AXS). Pawley refinements were carried out by fitting the background with a Chebychev function with ten parameters. The zero-point error or the sample displacement were refined, along with the lattice parameter of the phases and the crystallite size. The shape of the reflections was modeled through the fundamental parameter approach incorporated in the program, separating the instrumental and the sample contributions. Fit indicators $R_{\rm wp}$, $R_{\rm exp}$, and GoF (Goodness of Fit) were used to assess the quality of the refined structural models.

The OriginPro (OriginLab, MA, USA) [72] software was used to elaborate the data.

Scanning electron microscopy images were recorded with a Zeiss SUPRA 35VP instrument. FE-SEM images were taken using a primary beam acceleration voltage of 5.0 kV and a SE2 detector (secondary electrons).

UV-Visible reflectance spectra were acquired on a Cary 5000 spectrophotometer equipped with an integrating sphere.

Kelvin probe microscopy measurements were carried out in ambient air with an atomic force microscope MFP-3D by Asylum Research (Oxford Instruments, UK). A probe ASYELEC.02 was used, with nominal cantilever resonance frequency of 300 kHz, and tip coated with 25 nm thick Ti/Ir film. The scan was two-pass, with surface potential measured during the second pass at elevated height (typically 80 nm). The WF of the tip was first determined, by measuring the electrical surface potential V on highly-oriented pyrolitic

Appl. Sci. 2021, 11, 2016 10 of 13

graphite (HOPG), whose work function was assumed to be 4.6 eV. Measurements were carried out on a thick (bulk) layer of sample powder, pressed to form a solid pellet, finding consistent values, within the estimated uncertainty (± 100 mV). The obtained value resulted from averaging the means from n=4 images of typical 5 μ m scan size, in different sample locations.

Elemental analysis was carried out via Inductively Couple Plasma Optical Emission Spectrometry (ICP-OES), with an iCAP 7600 DUO (Thermo Fisher Scientific). Samples were weighted and digested in a single overnight step, in the case of Co_3O_4 -based samples, in a flask with aqua regia; MoO_3 -based samples were instead digested in a two-step process, first with HF and then with aqua regia. The digested samples were diluted to 10 mL using ultrapure Milli-Q water and filtered using a 0.45 μ m PTFE filter before the analysis. ICP-OES was used to determine the relative amount of vanadium with respect to the metal in the MO sample. Values were evaluated using the Qtegra software (Thermofisher).

Hydrothermal Synthesis of V-Doped Co₃O₄ and V-Doped MoO₃

For a typical hydrothermal synthesis of V-doped Co₃O₄ and V-doped MoO₃, adapting procedures reported in the literature [41,73], a given amount of metal precursor are dissolved in deionized water (10 mL). The amounts of cobalt acetate tetrahydrate (Carlo Erba, Milano, Italy, pur. >99%) and ammonium eptamolybdate tetrahydrate (Alfa Aesar, Kandel, Germany, pur. 99%) are respectively 0.3736 g and 0.58 g. At 0.15 M, solutions of cobalt acetate are added 0.0018, 0.0053, 0.0088, 0.0175, 0.0351 g of ammonium metavanadate (pur. 99%), with a molar ratio to the cobalt precursor of 0.01, 0.03, 0.05, 0.1 and 0.2, respectively, to have in the mixtures' different atomic ratios between the vanadium and cobalt precursor (1%, 3%, 5%, 10%, 20% at.). In a similar way, to the 0.05 M solutions of ammonium eptamolybdate 0.0746, 0.2237, 0.3728, 0.6984, 1.3968 g of ammonium metavanadate are added, with a molar ratio to the molybdenum precursor of 0.0746, 0.2237, 0.3728, 0.6984 and 1.3968, respectively, to achieve different atomic ratios between the vanadium and molybdenum precursor (1%, 3%, 5%, 10%, 20% at.). At the cobalt precursor solution, 0.135 g of oxalic acid (pur. >99%) with a molar ratio of 1:1 with respect to cobalt acetate are added, followed by stirring for 30 min. The molybdenum precursor solution is instead stirred for 20 min, then 275 µL of HCl 37% v/v are added (0.005 molar ratio to ammonium molybdate), and next the solution is stirred for other 20 min. Each solution is poured in a 23 mL A255AC PTFE cup (Parr Instrument Company, IL, USA).

Supplementary Materials: The following are available online at https://www.mdpi.com/2076-3417/11/5/2016/s1, Figure S1: Diffractograms of (a) Co_3O_4 -related compounds and (b) MoO_3 -doped samples. Figure S2. Reflectance spectra of (a) Co_3O_4 -related compounds and (b) MoO_3 -doped samples used for Tauc plot analysis. Figure S3. Diffractograms and corresponding Pawley refinements of (a) Co_3O_4 (Rwp = 9.27 %), (b) MoO_3 (Rwp = 9.41 %) and (c) MoO_3 :V 20% (at.) (Rwp = 9.47 %) with unit cell parameters of: $a = 3.9617 \pm 0.0004$ Å, $b = 13.8660 \pm 0.0013$ Å, $c = 3.6934 \pm 0.0003$ Å.

Author Contributions: Conceptualization, S.G., T.G. and F.L.; methodology, S.G., T.G. and F.L.; validation, S.G., T.G. and F.L.; formal analysis, T.G. and F.L.; investigation, M.C., P.D.F., F.B., F.T., F.D., M.S., M.P., S.G., T.G. and F.L.; resources, M.S., M.P., F.T., S.G., T.G.; data curation, T.G. and F.L.; writing—original draft preparation, M.C., P.D.F., T.G. and F.L.; writing-review and editing P.D.F., M.C., F.T., F.B., S.G., T.G. and F.L.; visualization, F.L. and T.G.; supervision, S.G., T.G. and F.L.; project administration, S.G., T.G. and F.L.; funding acquisition, S.G., T.G. and F.L. All authors have read and agreed to the published version of the manuscript.

Funding: P.D.F., F.L. and S.G. gratefully acknowledge the Interdepartmental Centre Giorgio Levi Cases for Energy Economics and Technology of the University of Padova for financial support within the project AMON-RA. S.G. thanks the Department of Excellence Project "NEXUS" for providing the P-XRD equipment and laboratory spaces. T.G. and M.C. thank the European Commission for the H2020 FET-PROACTIVE-EIC-07-2020 project LIGHT-CAP (project number 101017821) and the Verband der Chemischen Industrie e.V. for the "Fonds der Chemischen Industrie". F.T. and F.B. gratefully acknowledge for funding the PhD course in Molecular Sciences and the PhD Course in Science and Engineering of Materials and Nanostructures, University of Padova, Italy, respectively.

Appl. Sci. 2021, 11, 2016 11 of 13

Institutional Review Board Statement: Not applicable.

Informed Consent Statement: Not applicable.

Data Availability Statement: Not applicable.

Conflicts of Interest: The authors declare no conflict of interest.

References

1. Cox, P.A. *Transition Metal Oxides: An Introduction to Their Electronic Structure and Properties;* International Series of Monographs on Chemistry; OUP: Oxford, UK, 2010; ISBN 9780199588947.

- 2. Rao, C.N.R.; Raveau, B. *Transition Metal Oxides: Structure, Properties, and Synthesis of Ceramic Oxides,* 2nd ed.; Wiley VCH: Weinheim, Germany, 1998; ISBN 978-0-471-18971-8.
- 3. Greenwood, N.N.; Earnshaw, A. Chemistry of the Elements; Elsevier: Amsterdam, The Netherlands, 1997; ISBN 9780750633659.
- 4. Guo, T.; Yao, M.-S.; Lin, Y.-H.; Nan, C.-W. A comprehensive review on synthesis methods for transition-metal oxide nanostructures. *CrystEngComm* **2015**, *17*, 3551–3585. [CrossRef]
- 5. Danish, M.S.S.; Bhattacharya, A.; Stepanova, D.; Mikhaylov, A.; Grilli, M.L.; Khosravy, M.; Senjyu, T. A Systematic Review of Metal Oxide Applications for Energy and Environmental Sustainability. *Metals* **2020**, *10*, 1604. [CrossRef]
- 6. Bushell, M.; Beauchemin, S.; Kunc, F.; Gardner, D.; Ovens, J.; Toll, F.; Kennedy, D.; Nguyen, K.; Vladisavljevic, D.; Rasmussen, P.E.; et al. Characterization of Commercial Metal Oxide Nanomaterials: Crystalline Phase, Particle Size and Specific Surface Area. *Nanomaterials* **2020**, *10*, 1812. [CrossRef] [PubMed]
- 7. Della Giustina, G.; Zambon, A.; Lamberti, F.; Elvassore, N.; Brusatin, G. Straightforward Micropatterning of Oligonucleotides in Microfluidics by Novel Spin-On ZrO₂ Surfaces. *ACS Appl. Mater. Interfaces* **2015**, 7, 13280–13288. [CrossRef]
- 8. Lamberti, F.; Brigo, L.; Favaro, M.; Luni, C.; Zoso, A.; Cattelan, M.; Agnoli, S.; Brusatin, G.; Granozzi, G.; Giomo, M.; et al. Optoelectrochemical Biorecognition by Optically Transparent Highly Conductive Graphene-Modified Fluorine-Doped Tin Oxide Substrates. ACS Appl. Mater. Interfaces 2014, 6, 22769–22777. [CrossRef] [PubMed]
- 9. Chavali, M.S.; Nikolova, M.P. Metal oxide nanoparticles and their applications in nanotechnology. *SN Appl. Sci.* **2019**, *1*, 607. [CrossRef]
- 10. Pérez-Tomás, A.; Mingorance, A.; Tanenbaum, D.; Lira-Cantú, M. Chapter 8—Metal Oxides in Photovoltaics: All-Oxide, Ferroic, and Perovskite Solar Cells. In *Metal Oxides*; Lira-Cantu, M., Ed.; Elsevier: Amsterdam, The Netherlands, 2018; pp. 267–356. ISBN 978-0-12-811165-9.
- 11. Girardi, L.; Bardini, L.; Michieli, N.; Kalinic, B.; Maurizio, C.; Rizzi, G.; Mattei, G. Co3O4 Nanopetals on Si as Photoanodes for the Oxidation of Organics. *Surfaces* **2019**, 2, 41–53. [CrossRef]
- 12. Kim, J.; Iivonen, T.; Hämäläinen, J.; Kemell, M.; Meinander, K.; Mizohata, K.; Wang, L.; Räisänen, J.; Beranek, R.; Leskelä, M.; et al. Low-Temperature Atomic Layer Deposition of Cobalt Oxide as an Effective Catalyst for Photoelectrochemical Water-Splitting Devices. *Chem. Mater.* **2017**, *29*, 5796–5805. [CrossRef]
- 13. Mai, L.; Yang, F.; Zhao, Y.; Xu, X.; Xu, L.; Hu, B.; Luo, Y.; Liu, H. Molybdenum oxide nanowires: Synthesis & properties. *Mater. Today* **2011**, *14*, 346–353.
- 14. Haber, J.; Lalik, E. Catalytic properties of MoO3 revisited. Catal. Today 1997, 33, 119–137. [CrossRef]
- 15. Mane, A.A.; Nikam, S.A.; Moholkar, A.V. NO2 gas sensing properties of sprayed composite porous MoO3-V2O5 thin films. *Mater. Chem. Phys.* **2018**, *216*, 294–304. [CrossRef]
- 16. Bhatia, S.; Khanna, A. Structural and Optical Properties of Molybdenum Trioxide Thin Films. AIP Conf. Proc. 2015, 1665, 080057.
- 17. Guo, Y.; Robertson, J. Origin of the high work function and high conductivity of MoO 3. *Appl. Phys. Lett.* **2014**, 105, 222110. [CrossRef]
- 18. Tao, C.; Ruan, S.; Zhang, X.; Xie, G.; Shen, L.; Kong, X.; Dong, W.; Liu, C.; Chen, W. Performance improvement of inverted polymer solar cells with different top electrodes by introducing a MoO3 buffer layer. *Appl. Phys. Lett.* **2008**, *93*, 193307. [CrossRef]
- 19. De Melo, O.; Torres-Costa, V.; Climent-Font, A.; Galán, P.; Ruediger, A.; Sánchez, M.; Calvo-Mola, C.; Santana, G.; Torres-Costa, V. Optical and electrical properties of MoO2 and MoO3 thin films prepared from the chemically driven isothermal close space vapor transport technique. *J. Phys. Condens. Matter* 2019, 31, 295703. [CrossRef] [PubMed]
- 20. Prasad, A.K.; Gouma, P.I.; Kubinski, D.J.; Visser, J.H.; Soltis, R.E.; Schmitz, P.J. Reactively sputtered MoO3 films for ammonia sensing. *Thin Solid Films* **2003**, *436*, 46–51. [CrossRef]
- 21. Kupfer, B.; Majhi, K.; Keller, D.A.; Bouhadana, Y.; Rühle, S.; Barad, H.N.; Anderson, A.Y.; Zaban, A. Thin Film Co₃O₄/TiO₂ Heterojunction Solar Cells. *Adv. Energy Mater.* **2015**, *5*, 1401007. [CrossRef]
- 22. Rühle, S.; Anderson, A.Y.; Barad, H.-N.; Kupfer, B.; Bouhadana, Y.; Rosh-Hodesh, E.; Zaban, A. All-Oxide Photovoltaics. *J. Phys. Chem. Lett.* **2012**, *3*, 3755–3764. [CrossRef]
- Zhou, Y.; Zhang, X.; Lu, X.; Gao, X.; Gao, J.; Shui, L.; Wu, S.; Liu, J. Promoting the Hole Extraction with Co₃O₄ Nanomaterials for Efficient Carbon-Based CsPbI 2 Br Perovskite Solar Cells. Sol. RRL 2019, 3, 1800315. [CrossRef]
- 24. Bashir, A.; Shukla, S.; Lew, J.H.; Shukla, S.; Bruno, A.; Gupta, D.; Baikie, T.; Patidar, R.; Akhter, Z.; Priyadarshi, A.; et al. Spinel Co 3 O 4 nanomaterials for efficient and stable large area carbon-based printed perovskite solar cells. *Nanoscale* **2018**, *10*, 2341–2350. [CrossRef] [PubMed]

Appl. Sci. 2021, 11, 2016 12 of 13

25. Righetto, M.; Meggiolaro, D.; Rizzo, A.; Sorrentino, R.; He, Z.; Meneghesso, G.; Sum, T.C.; Gatti, T.; Lamberti, F. Coupling halide perovskites with different materials: From doping to nanocomposites, beyond photovoltaics. *Prog. Mater. Sci.* **2020**, *110*, 100639. [CrossRef]

- 26. Yuhas, B.D.; Zitoun, D.O.; Pauzauskie, P.J.; He, R.; Yang, P. Transition-Metal Doped Zinc Oxide Nanowires. *Angew. Chem. Int. Ed.* **2006**, 45, 420–423. [CrossRef] [PubMed]
- 27. Jansons, A.W.; Koskela, K.M.; Crockett, B.M.; Hutchison, J.E. Transition Metal-Doped Metal Oxide Nanocrystals: Efficient Substitutional Doping through a Continuous Growth Process. *Chem. Mater.* **2017**, 29, 8167–8176. [CrossRef]
- 28. Stavale, F.; Shao, X.; Nilius, N.; Freund, H.-J.; Prada, S.; Giordano, L.; Pacchioni, G. Donor Characteristics of Transition-Metal-Doped Oxides: Cr-Doped MgO versus Mo-Doped CaO. *J. Am. Chem. Soc.* **2012**, *134*, 11380–11383. [CrossRef] [PubMed]
- 29. Hermann, K.; Witko, M.; Druzinic, R.; Chakrabarti, A.; Tepper, B.; Elsner, M.; Gorschlüter, A.; Kuhlenbeck, H.; Freund, H.J. Properties and identification of oxygen sites at the V2O5(010) surface: Theoretical cluster studies and photoemission experiments. *J. Electron Spectrosc. Relat. Phenom.* **1999**, 98–99, 245–256. [CrossRef]
- 30. Qu, G.; Wang, J.; Liu, G.; Tian, B.; Su, C.; Chen, Z.; Rueff, J.-P.; Wang, Z. Vanadium Doping Enhanced Electrochemical Performance of Molybdenum Oxide in Lithium-Ion Batteries. *Adv. Funct. Mater.* **2019**, 29, 1805227. [CrossRef]
- 31. Singh, P.K.; Singh, N.; Singh, M.; Tandon, P.; Singh, S.K. Preparation of Nanostructured Co3O4 and Ru-Doped Co₃O₄ and Their Applicability in Liquefied Petroleum Gas Sensing. *J. Mater. Eng. Perform.* **2019**, *28*, 7592–7601. [CrossRef]
- 32. Xu, L.; Wang, Z.; Wang, J.; Xiao, Z.; Huang, X.; Liu, Z.; Wang, S. N-doped nanoporous Co 3 O 4 nanosheets with oxygen vacancies as oxygen evolving electrocatalysts. *Nanotechnology* **2017**, 28, 165402. [CrossRef] [PubMed]
- 33. Shaban, M.; El Sayed, A.M. Influence of the spin deposition parameters and La/Sn double doping on the structural, optical, and photoelectrocatalytic properties of CoCo2O4 photoelectrodes. *Sol. Energy Mater. Sol. Cells* **2020**, 217, 110705. [CrossRef]
- 34. Venkatesh, R.; Dhas, C.R.; Sivakumar, R.; Dhandayuthapani, T.; Subramanian, B.; Sanjeeviraja, C.; Raj, A.M.E. Tailoring the physical properties and electrochromic performance of nebulizer spray coated Co3O4 films through copper doping. *Solid State Ion.* 2019, 334, 5–13. [CrossRef]
- 35. Švegl, F.; Orel, B.; Grabec-Švegl, I.; Kaučič, V. Characterization of spinel Co3O4 and Li-doped Co3O4 thin film electrocatalysts prepared by the sol–gel route. *Electrochim. Acta* **2000**, *45*, 4359–4371. [CrossRef]
- 36. Xing, Z.; Wu, H.; Wu, L.; Wang, X.; Zhong, H.; Li, F.; Shi, J.; Song, D.; Xiao, W.; Jiang, C.; et al. A multifunctional vanadium-doped cobalt oxide layer on silicon photoanodes for efficient and stable photoelectrochemical water oxidation. *J. Mater. Chem. A* **2018**, *6*, 21167–21177. [CrossRef]
- 37. El-Shobaky, G.A.; Turky, A.E.-M.M. Catalytic decomposition of H₂O₂ on Co₃O₄ doped with MgO and V2O5. *Colloids Surf. A Physicochem. Eng. Asp.* **2000**, *170*, 161–172. [CrossRef]
- 38. Ali, F.; Khalid, N.R. Effect of calcination temperature on structural, morphological and electrochemical properties of Sn doped Co3O4 nanorods. *Ceram. Int.* **2020**, *46*, 24137–24146. [CrossRef]
- 39. Aadil, M.; Zulfiqar, S.; Shahid, M.; Haider, S.; Shakir, I.; Warsi, M.F. Binder free mesoporous Ag-doped Co3O4 nanosheets with outstanding cyclic stability and rate capability for advanced supercapacitor applications. *J. Alloys Compd.* **2020**, *844*, 156062. [CrossRef]
- 40. Jiang, T.; Yin, N.; Bai, Z.; Dai, P.; Yu, X.; Wu, M.; Li, G. Wet chemical synthesis of S doped Co3O4 nanosheets/reduced graphene oxide and their application in dye sensitized solar cells. *Appl. Surf. Sci.* **2018**, 450, 219–227. [CrossRef]
- 41. Wei, R.; Bu, X.; Gao, W.; Villaos, R.A.B.; Macam, G.; Huang, Z.-Q.; Lan, C.; Chuang, F.-C.; Qu, Y.; Ho, J.C. Engineering Surface Structure of Spinel Oxides via High-Valent Vanadium Doping for Remarkably Enhanced Electrocatalytic Oxygen Evolution Reaction. ACS Appl. Mater. Interfaces 2019, 11, 33012–33021. [CrossRef]
- 42. Peelaers, H.; Chabinyc, M.L.; Van de Walle, C.G. Controlling n -Type Doping in MoO 3. *Chem. Mater.* **2017**, 29, 2563–2567. [CrossRef]
- 43. Patil, M.K.; Gaikwad, S.H.; Mukherjee, S.P. Phase- and Morphology-Controlled Synthesis of Tunable Plasmonic MoO₃-x Nanomaterials for Ultrasensitive Surface-Enhanced Raman Spectroscopy Detection. *J. Phys. Chem. C* **2020**, 124, 21082–21093. [CrossRef]
- 44. Shen, J.; Guo, S.; Chen, C.; Sun, L.; Wen, S.; Chen, Y.; Ruan, S. Synthesis of Ni-doped A-MoO3 nanolamella and their improved gas sensing properties. *Sens. Actuators B Chem.* **2017**, 252, 757–763. [CrossRef]
- 45. Rammal, M.B.; Omanovic, S. Synthesis and characterization of NiO, MoO3, and NiMoO4 nanostructures through a green, facile method and their potential use as electrocatalysts for water splitting. *Mater. Chem. Phys.* **2020**, 255, 123570. [CrossRef]
- 46. Ahmad, H.; Afzal, N.; Rafique, M.; Ahmed, A.A.; Ahmad, R.; Khaliq, Z. Post-deposition annealed MoO3 film based high performance MSM UV photodetector fabricated on Si (100). *Ceram. Int.* **2020**, *46*, 20477–20487. [CrossRef]
- 47. Phuruangrat, A.; Chen, J.S.; Lou, X.W.; Yayapao, O.; Thongtem, S.; Thongtem, T. Hydrothermal synthesis and electrochemical properties of α-MoO 3 nanobelts used as cathode materials for Li-ion batteries. *Appl. Phys. A Mater. Sci. Process.* **2012**, 107, 249–254. [CrossRef]
- 48. Yang, X.; Ding, H.; Zhang, D.; Yan, X.; Lu, C.; Qin, J.; Zhang, R.; Tang, H.; Song, H. Hydrothermal synthesis of MoO3 nanobelt-graphene composites. *Cryst. Res. Technol.* **2011**, *46*, 1195–1201. [CrossRef]
- 49. Qin, P.; Fang, G.; Cheng, F.; Ke, W.; Lei, H.; Wang, H.; Zhao, X. Sulfur-doped molybdenum oxide anode interface layer for organic solar cell application. *ACS Appl. Mater. Interfaces* **2014**, *6*, 2963–2973. [CrossRef]

Appl. Sci. 2021, 11, 2016 13 of 13

50. Layegh, M.; Ghodsi, F.E.; Hadipour, H. Experimental and theoretical study of Fe doping as a modifying factor in electrochemical behavior of mixed-phase molybdenum oxide thin films. *Appl. Phys. A Mater. Sci. Process.* **2020**, *126*, 1–14. [CrossRef]

- 51. Li, Z.; Wang, W.; Zhao, Z.; Liu, X.; Song, P. Facile synthesis and enhanced trimethylamine sensing performances of W-doped MoO3 nanobelts. *Mater. Sci. Semicond. Process.* **2017**, *66*, 33–38. [CrossRef]
- 52. Cheyns, D.; Kam, B.; Vasseur, K.; Heremans, P.; Rand, B.P. Structure induced conductivity enhancement in metal-doped molybdenum oxide thin films. *J. Appl. Phys.* **2013**, *113*, 043109. [CrossRef]
- 53. Deori, K.; Deka, S. Morphology oriented surfactant dependent CoO and reaction time dependent Co3O4 nanocrystals from single synthesis method and their optical and magnetic properties. *CrystEngComm* **2013**, *15*, 8465. [CrossRef]
- 54. Vijayakumar, Y.; Mani, G.K.; Reddy, M.V.R.; Rayappan, J.B.B. Nanostructured flower like V2O5 thin films and its room temperature sensing characteristics. *Ceram. Int.* **2015**, *41*, 2221–2227. [CrossRef]
- 55. Lester, E.; Aksomaityte, G.; Li, J.; Gomez, S.; Gonzalez-Gonzalez, J.; Poliakoff, M. Controlled continuous hydrothermal synthesis of cobalt oxide (Co₃O₄) nanoparticles. *Prog. Cryst. Growth Charact. Mater.* **2012**, *58*, 3–13. [CrossRef]
- Yao, Y.; Yang, Z.; Sun, H.; Wang, S. Hydrothermal Synthesis of Co₃O₄–Graphene for Heterogeneous Activation of Peroxymonosulfate for Decomposition of Phenol. *Ind. Eng. Chem. Res.* 2012, 51, 14958–14965. [CrossRef]
- 57. Liu, J.; Jiang, J.; Cheng, C.; Li, H.; Zhang, J.; Gong, H.; Fan, H.J. Co₃O₄ Nanowire@MnO2 Ultrathin Nanosheet Core/Shell Arrays: A New Class of High-Performance Pseudocapacitive Materials. *Adv. Mater.* **2011**, 23, 2076–2081. [CrossRef]
- 58. Chen, Z.; Cummins, D.; Reinecke, B.N.; Clark, E.; Sunkara, M.K.; Jaramillo, T.F. Core–shell MoO₃–MoS₂ Nanowires for Hydrogen Evolution: A Functional Design for Electrocatalytic Materials. *Nano Lett.* **2011**, *11*, 4168–4175. [CrossRef]
- 59. Chiang, T.; Yeh, H. The Synthesis of α-MoO₃ by Ethylene Glycol. *Materials* **2013**, *6*, 4609–4625. [CrossRef]
- 60. Barreca, D.; Massignan, C.; Daolio, S.; Fabrizio, M.; Piccirillo, C.; Armelao, L.; Tondello, E. Composition and Microstructure of Cobalt Oxide Thin Films Obtained from a Novel Cobalt(II) Precursor by Chemical Vapor Deposition. *Chem. Mater.* **2001**, 13, 588–593. [CrossRef]
- 61. Xiao, Z.; Wang, Y.; Huang, Y.-C.; Wei, Z.; Dong, C.-L.; Ma, J.; Shen, S.; Li, Y.; Wang, S. Filling the oxygen vacancies in Co₃O₄ with phosphorus: An ultra-efficient electrocatalyst for overall water splitting. *Energy Environ. Sci.* 2017, 10, 2563–2569. [CrossRef]
- 62. Xiao, Z.; Huang, Y.-C.; Dong, C.-L.; Xie, C.; Liu, Z.; Du, S.; Chen, W.; Yan, D.; Tao, L.; Shu, Z.; et al. Operando Identification of the Dynamic Behavior of Oxygen Vacancy-Rich Co₃O₄ for Oxygen Evolution Reaction. *J. Am. Chem. Soc.* **2020**, *142*, 12087–12095. [CrossRef] [PubMed]
- 63. Tong, Y.; Mao, H.; Xu, Y.; Liu, J. Oxygen vacancies confined in Co₃O₄ quantum dots for promoting oxygen evolution electrocatalysis. *Inorg. Chem. Front.* **2019**, *6*, 2055–2060. [CrossRef]
- 64. Kim, M.; Alfano, A.; Perotto, G.; Serri, M.; Dengo, N.; Mezzetti, A.; Gross, S.; Prato, M.; Salerno, M.; Rizzo, A.; et al. Moisture resistance in perovskite solar cells attributed to a water-splitting layer. *Commun. Mater.* **2021**, *2*, 6. [CrossRef]
- 65. Makuła, P.; Pacia, M.; Macyk, W. How to Correctly Determine the Band Gap Energy of Modified Semiconductor Photocatalysts Based on UV-Vis Spectra. *J. Phys. Chem. Lett.* **2018**, *9*, 6814–6817. [CrossRef] [PubMed]
- 66. George, G.; Anandhan, S. A comparative study on the physico–chemical properties of sol–gel electrospun cobalt oxide nanofibres from two different polymeric binders. *RSC Adv.* **2015**, *5*, 81429–81437. [CrossRef]
- 67. Vogt, K.T.; Malmberg, C.E.; Buchanan, J.C.; Mattson, G.W.; Brandt, G.M.; Fast, D.B.; Cheong, P.H.-Y.; Wager, J.F.; Graham, M.W. Ultrabroadband density of states of amorphous In-Ga-Zn-O. *Phys. Rev. Res.* **2020**, *2*, 033358. [CrossRef]
- 68. Shannon, R.D. Revised effective ionic radii and systematic studies of interatomic distances in halides and chalcogenides. *Acta Crystallogr. Sect. A* **1976**, 32, 751–767. [CrossRef]
- 69. Gerling, L.; Mahato, S.; Voz, C.; Alcubilla, R.; Puigdollers, J. Characterization of Transition Metal Oxide/Silicon Heterojunctions for Solar Cell Applications. *Appl. Sci.* **2015**, *5*, 695–705. [CrossRef]
- 70. DIFFRAC.EVA, Bruker. 2018. Available online: https://www.bruker.com/evan.d (accessed on 2 October 2020).
- 71. Coelho, A.A. TOPAS-Academic; Coelho Software: Brisbane, Australia, 2007.
- 72. OriginPro, Version 2021; OriginLab Corporation: Northampton, MA, USA, 2021.
- 73. Liu, X.; Gao, J.; Chen, Y.; Li, C.; Chen, J.; Qu, W.; Chen, X.; Ma, Z.; Tang, X. Rational Design of Alkali-Resistant NO Reduction Catalysts using a Stable Hexagonal V-Doped MoO 3 Support for Alkali Trapping. *ChemCatChem* **2018**, *10*, 3999–4003. [CrossRef]